imall

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



Contact us

Tel: +86-755-8981 8866 Fax: +86-755-8427 6832 Email & Skype: info@chipsmall.com Web: www.chipsmall.com Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China





v03.0410



HMC334LP4 / 334LP4E

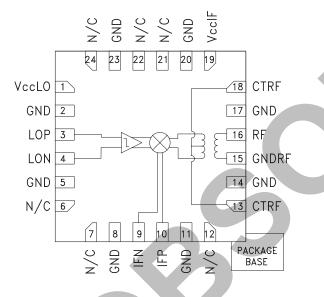
SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Typical Applications

The HM334LP4(E) is ideal for:

- Basestations & Repeaters
- GSM, GPRS & Edge
- CDMA, W-CDMA & TD-SCDMA
- WiMAX & LTE

Functional Diagram



Features

Conversion Loss: 0 dB LO to RF Isolation: 48 dB Single-Ended LO Drive: -6 to +6 dBm Input IP3: +26 dBm SSB Noise Figure: 11 dB On-Chip RF Balun 24 Lead 4x4mm QFN Package: 16 mm²

General Description

The HMC334LP4(E) is a low noise, wideband downconverter RFIC which is ideal for Cellular/3G and WiMAX/4G applications from 0.6 to 2.7 GHz. The LO input accepts drive levels from -6 to +6 dBm while the RFIC provides 48 dB of LO to RF isolation, and 0 dB conversion loss. The HMC334LP4(E) will support an IF output bandwidth of up to 600 MHz and consumes only 173 mA from a +5V supply. This wideband active mixer also provides excellent performance in the presence of high level "Blocker" signals, making it ideal for receiver applications in demanding environments.

Electrical Specifications, $T_{A} = +25 \text{ °C}, LO = 0 \text{ dBm}^{*}, V_{SLO} = V_{SIF} = +5V, IF = 240 \text{ MHz}$

Parameter	Min.	Тур.	Max.	Units
Frequency Range, RF		0.6 - 2.7		
Frequency Range, LO	0.35 - 3.0		GHz	
Frequency Range, IF		1 - 600		MHz
Conversion Gain (IF XFMR Included)		-1		dB
SSB Noise Figure		11		dB
LO to RF Isolation		48		dB
IF Output Impedance (Diff)		200		Ohms
IP3 (Input)		+26		dBm
1 dB Compression (Input)		12		dBm
rive Input Level -6 to +6		dBm		
Supply Current		173	225	mA

*Unless otherwise noted all measurements with R1 = 13 Ohms and single-ended 50 Ohm IF output with Port J2 or J3 shorted to ground.

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



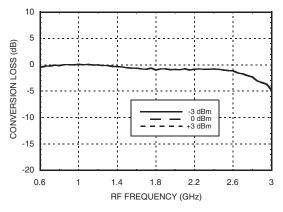
DOWNCONVERTER, 0.6 - 2.7 GHz

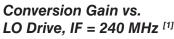
SiGe WIDEBAND

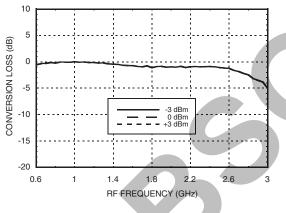
v03.0410

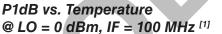


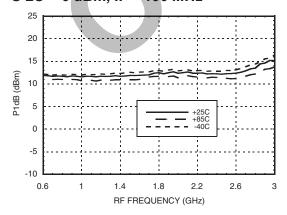
Conversion Gain vs. LO Drive, IF = 100 MHz^[1]







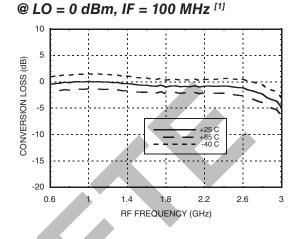




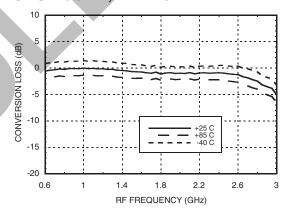
[1] LO < RF * Unless otherwise noted all measurements with R1= 13 Ohms

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

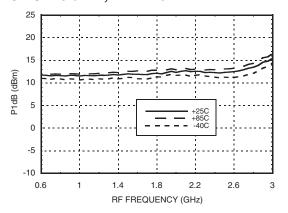
Conversion Gain vs. Temperature



Conversion Gain vs. Temperature @ LO = 0 dBm, IF = 240 MHz^[1]



P1dB vs. Temperature @ LO = 0 dBm, IF = 240 MHz ^[1]

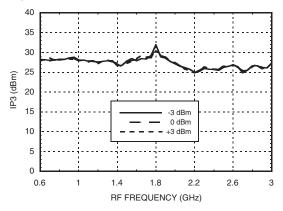




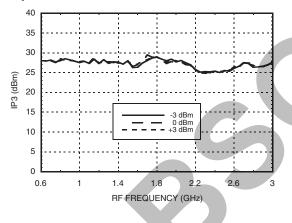
v03.0410



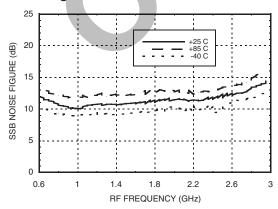
Input IP3 vs. LO Drive, IF = 100 MHz [1]



Input IP3 vs. LO Drive, IF = 240 MHz [1]



Noise Figure ^[1]



[1] LO < RF

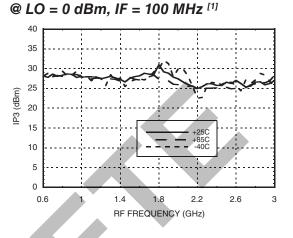
* Unless otherwise noted all measurements with R1= 13 Ohms

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

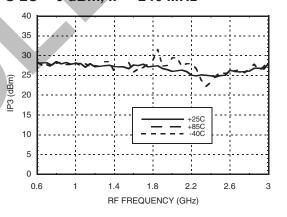
HMC334LP4 / 334LP4E

SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

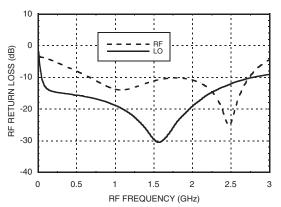
Input IP3 vs. Temperature



Input IP3 vs. Temperature @ LO = 0 dBm, IF = 240 MHz^[1]



RF Return Loss @ LO = 0 dBm [1]





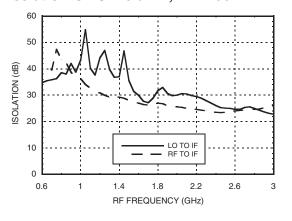
DOWNCONVERTER, 0.6 - 2.7 GHz

SiGe WIDEBAND

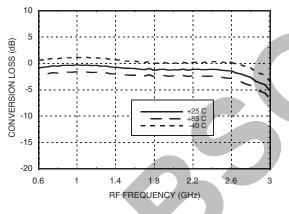
v03.0410



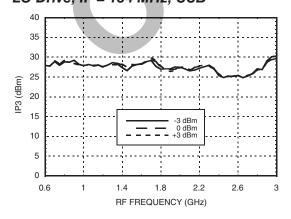
Isolation @ LO = 0 dBm, IF = 100 MHz ^[1]



Conversion Gain vs. Temperature, IF = 184 MHz, USB^[2]



Input IP3 vs. LO Drive, IF = 184 MHz, USB ^[2]

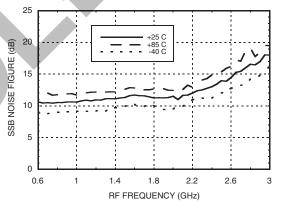




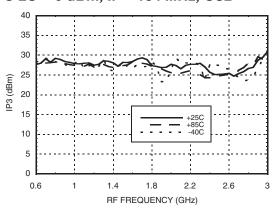
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

LO - RF Isolation @ LO = 0 dBm^[1] 60 50 **ISOLATION (dB)** 40 30 100MH 20 IF = 240MHz 10 0 0.6 2.2 2.6 3 1.4 1.8 RF FREQUENCY (GHz)

Noise Figure, IF = 184 MHz, USB^[2]



Input IP3 vs. Temperature @ LO = 0 dBm, IF = 184 MHz, USB ^[2]



MIXERS - DOWNCONVERTERS - SMT



v03.0410



Absolute Maximum Ratings

RF Input (VsLo = VsIF= +5V)	+21 dBm
LO Drive (VsLo = VsIF= +5V)	+12 dBm
VccLO, VccIF	+6 Vdc
Channel Temperature	150 °C
Continuous Pdiss (T = 85°C) (derate 27.8 mW/°C above 85°C)	1.8 W
Thermal Resistance (channel to ground paddle)	36 °C/W
Storage Temperature	-65 to 150 °C
Operating Temperature	-40 to 85 °C

HMC334LP4 / 334LP4E

SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Typical Supply Current vs. Supply Voltage

VSLO = VSIF (V)	Islo + Isif (mA)
+4.5	146
+5.0	173
+5.5	200

Downconverter will operate over full voltage range shown above.

ELECTROSTATIC SENSITIVE DEVICE OBSERVE HANDLING PRECAUTIONS

Outline Drawing

BOTTOM VIEW .161 4.10 .153 3.90 PIN 24 -.016 [0.40] REF .012 0.30 .007 0.18 .008 [0.20] MIN 19 PIN 1 18 2.56 2.44 Г 00 HNNN .022 .017 0.56 XXXX 10.00. 161 C 13 6 12 **EXPOSED** 7 LOT NUMBER .116 2.95 GROUND PADDLE 1.00 0.80 .039 SQUARE 0.05 .002 .000 NOTES: SEATING 1. LEADFRAME MATERIAL: COPPER ALLOY PLANE 2. DIMENSIONS ARE IN INCHES [MILLIMETERS] __.003[0.08]|C 3. LEAD SPACING TOLERANCE IS NON-CUMULATIVE. -C-|

- 4. PAD BURR LENGTH SHALL BE 0.15mm MAXIMUM.
- PAD BURR HEIGHT SHALL BE 0.05mm MAXIMUM.
- 5. PACKAGE WARP SHALL NOT EXCEED 0.05mm.
- 6. ALL GROUND LEADS AND GROUND PADDLE MUST BE SOLDERED TO PCB RF GROUND.
- 7. REFER TO HITTITE APPLICATION NOTE FOR SUGGESTED LAND PATTERN.

Package Marking [3] Part Number Package Body Material Lead Finish **MSL** Rating H334 MSL1 [1] HMC334LP4 Low Stress Injection Molded Plastic Sn/Pb Solder XXXX H334 MSL1 [2] HMC334LP4E **RoHS-compliant Low Stress Injection Molded Plastic** 100% matte Sn XXXX

[1] Max peak reflow temperature of 235 $^\circ\text{C}$

Package Information

[2] Max peak reflow temperature of 260 °C

[3] 4-Digit lot number XXXX

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

For price, delivery, and to place orders: Analog Devices, Inc., One Technology Way, P.O. Box 9106, Norwood, MA 02062-9106 Phone: 781-329-4700 • Order online at www.analog.com Application Support: Phone: 1-800-ANALOG-D

9



v03.0410



SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Pin Descriptions

Pin Number	Function	Description	Interface Schematic
1	VccLO	Supply for LO Amplifier. Draws approximately 120mA from VSLO. A 13 Ohm resistor (R1) must be connected externally between the VSLO supply and the VccLO pin. See evaluation PCB schematic.	VccLO O LO DRIVE
2, 5, 8, 11, 14, 17, 20, 23	GND	These pins and the ground paddle should be connected to a high quality RF/DC ground.	
3	LOP	LO Input Port. This pin needs a DC blocking capacitor. (Typical voltage on this pin will be 1.5 - 1.8V)	VecLO O
4	LON	For single ended applications, this pin should be AC grounded	
6, 7, 12, 21, 22, 24	N/C	The pins are not connected internally; however, all data shown herein was measured with these pins connected to RF/DC ground externally.	
9, 10	IFN, IFP	Differential baseband outputs, 200 ohm differential output impedance. Each port should draw approximately 25mA from VSIF without LO power and 28mA from VSIF with LO power on. For single-ended 50 Ohm operation, port J2 or J3 should be shorted to RF/DC ground. See evaluation PCB schematic.	
13, 18	CTRF	Center tap of the RF transformer. Biased at 2.2V when con- nected to ground through two 91 ohm resistors.	
15	GNDRF	Pin to be connected to a high quality RF/DC ground. Also can be used to drive the RF port differentially if needed.	
16	RF	50 Ohms impedance can be matched from 600 - 3000 MHz.	3 E
19	VccIF	Supply decoupling for the mixer stage. (Typical voltage on this pin will be 4.8V) Connect C3 to a high quality RF/DC ground per evaluation PCB schematic.	

9

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.

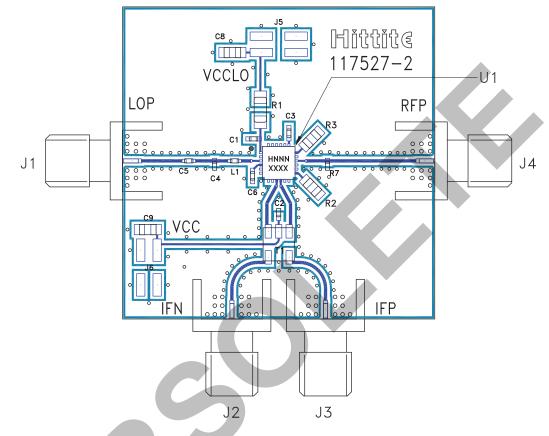


v03.0410



SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz

Evaluation PCB



List of Materials for Evaluation PCB 117528 [1]

Item	Description
J1 - J4	Johnson SMA Connector
J5 - J6	2mm SMT
C1 - C3	1000 pF Capacitor, 0402 Pkg.
C4	0.3 pF Capacitor, 0402 Pkg.
C5	100 pF Capacitor, 0402 Pkg.
C6	10 KpF Capacitor, 0402 Pkg.
C7	1.3 pF Capacitor, 0402 Pkg.
C8, C9	0.1 μF Capacitor, 0805 Pkg.
L1	2.7 nH Chip Inductor, 0603 Pkg.
L2	2 nH Chip Inductor, 0603 Pkg.
R1	13 Ohm Resistor, 1206 Pkg.
R2, R3	91 Ohm Resistor, 0805 Pkg.
T1	M/A-Com 4:1 Balun, MABAES0061
U1	HMC334LP4 / HMC334LP4E
PCB [2]	117527 Evaluation Board

[1] Reference this number when ordering complete evaluation PCB [2] Circuit Board Material: Rogers 4350 The circuit board used in the final application should use RF circuit design techniques. Signal lines should have 50 Ohm impedance while the package ground leads and exposed paddle should be connected directly to the ground plane similar to that shown. A sufficient number of via holes should be used to connect the top and bottom ground planes. The evaluation circuit board shown is available from Hittite upon request.

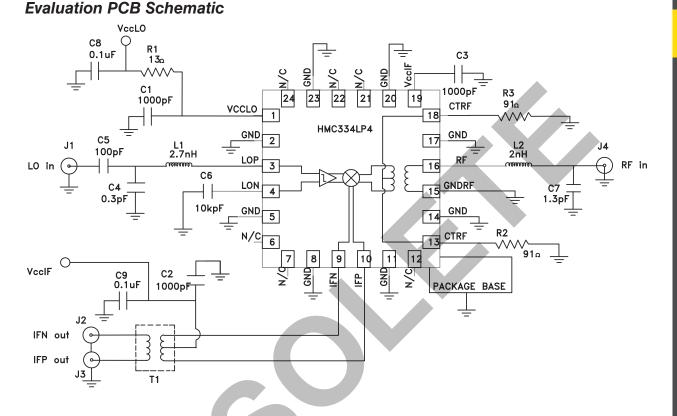
Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.



v03.0410



SiGe WIDEBAND DOWNCONVERTER, 0.6 - 2.7 GHz



Note: For single-ended 50 Ohms operation, port J2 or J3 should be shorted to RF/DC ground.

MIXERS - DOWNCONVERTERS - SMT

9

Information furnished by Analog Devices is believed to be accurate and reliable. However, no responsibility is assumed by Analog Devices for its use, nor for any infringements of patents or other rights of third parties that may result from its use. Specifications subject to change without notice. No license is granted by implication or otherwise under any patent or patent rights of Analog Devices. Trademarks and registered trademarks are the property of their respective owners.